



**Product data sheet** 

### 1. Product profile

#### 1.1 General description

Four planar PIN diode array in SOT363 small SMD plastic package.

#### 1.2 Features

- High voltage current controlled RF resistor for RF attenuators
- Low diode capacitance
- Very low series inductance
- Low distortion

#### 1.3 Applications

- RF attenuators
- (SAT) TV applications
- Car radio applications

### 2. Pinning information

#### Table 1. **Discrete pinning** Pin Description Simplified outline Symbol 1 anode diode 1 2 cathode diode 2 3 anode diode 3 / cathode diode 4 4 anode diode 4 3 5 cathode diode 3 sym118 6 anode diode 2 / cathode diode 1

### 3. Ordering information

#### Table 2.Ordering information

Type number	Package		
	Name	Description	Version
BAP70AM	-	plastic surface-mounted package; 6 leads	SOT363



### 4. Marking

Table 3. Marking	
Type number	Marking code
BAP70AM	N9

## 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			-		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>R</sub>	reverse voltage		-	50	V
I <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{sp} = 90 \ ^{\circ}C$	-	300	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

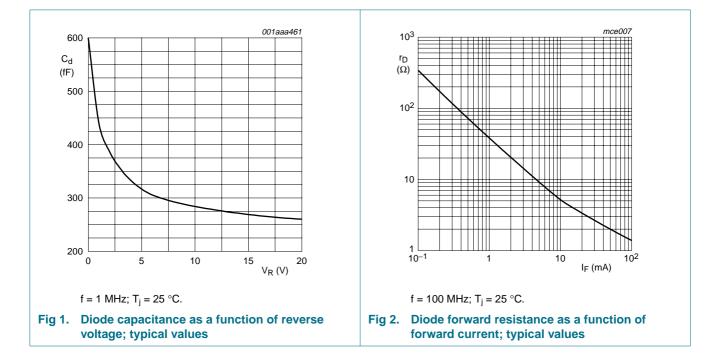
### 6. Thermal characteristics

Table 5.	Thermal characteristics				
Symbol	Parameter	Conditions	Тур	Unit	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		260	K/W	

Silicon PIN diode array

#### **Characteristics** 7.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA	-	0.9	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 50 V	-	-	<100	nA
C <sub>d</sub>	diode capacitance	see <u>Figure 1;</u> f = 1 MHz;	-			
		$V_R = 0 V$	-	570	-	fF
		$V_R = 1 V$	-	400	-	fF
		$V_R = 5 V$	-	270	-	fF
		V <sub>R</sub> = 20 V	-	200	250	fF
r <sub>D</sub> d	diode forward resistance	see <u>Figure 2</u> ; f = 100 MHz;	-			
		I <sub>F</sub> = 0.5 mA	-	77	100	Ω
		I <sub>F</sub> = 1 mA	-	40	50	Ω
		I <sub>F</sub> = 10 mA	-	5.4	7	Ω
		I <sub>F</sub> = 100 mA	-	1.4	1.9	Ω
τ∟	charge carrier life time	when switched from $I_F$ = 10 mA to $I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA	-	1.25	-	μs
Ls	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.6	-	nH



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### 8. Package outline

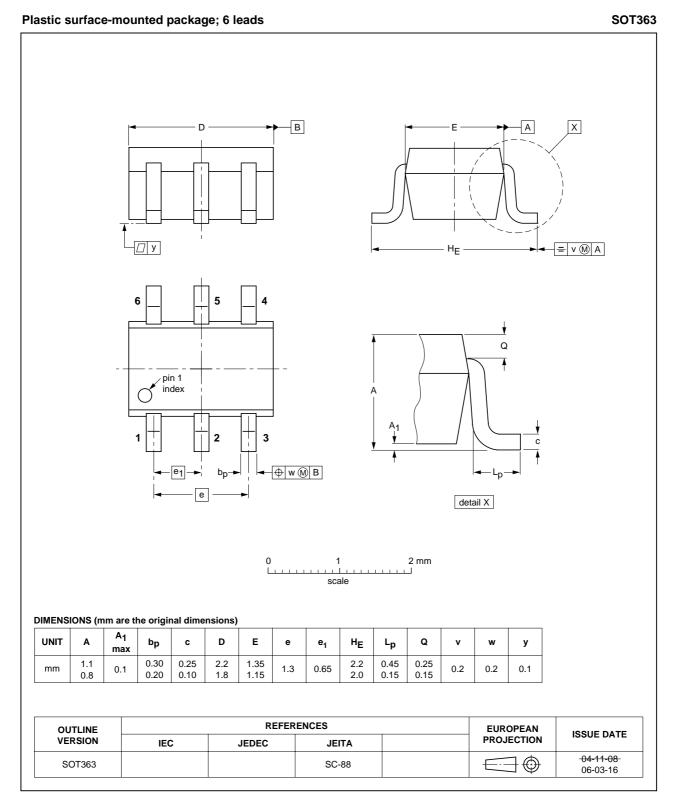


Fig 3. Package outline SOT363

Silicon PIN diode array

### 9. Abbreviations

Table 7. Abbreviations		
Acronym	Description	
PIN	P-type, Intrinsic, N-type	
SMD	Surface Mounted Device	
RF	Radio Frequency	
SAT	Satellite	

## **10. Revision history**

Table 8. Revisi	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP70AM_1	20061120	Product data sheet	-	-	

### **11. Legal information**

#### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 20 November 2006 Document identifier: BAP70AM\_1

